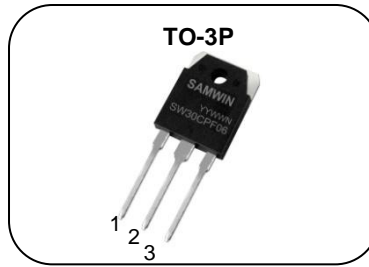


## DIODE

### Features

- Ultrafast recovery time
- Low forward voltage drop
- 150 °C operating junction temperature
- Low leakage current
- Designed and qualified according to JEDEC-JESD47

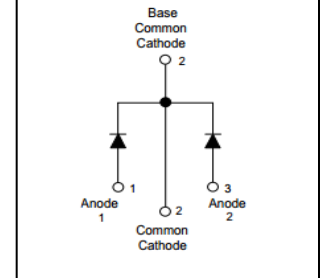


1. Anode 2. Gathode 3. Anode

**VR : 600V**

**IF(AV) : 30A**

**VF at IF : 1.4V**



### General Description

This FRED is designed with optimized performance of forward voltage drop and ultrafast recovery time. The platinum doped life time control, guarantee the best overall performance ruggedness and reliability characteristics. This devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as freewheeling diode in low voltage inverters. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element.

### Order Codes

Item	Sales Type	Marking	Package	Packaging
1	SW W 30CPF06	SW30CPF06	TO-3P	TUBE

### Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_R$	Repetitive peak reverse voltage	600	V
$I_{F(AV)}$	Average rectified forward current (@ $T_C=150^\circ\text{C}$ )	30	A
TJ, TStg	Operating junction and storage temperatures	-55 ~ + 150	°C

Electrical characteristic (  $T_C = 25^\circ\text{C}$  unless otherwise specified )

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_R$	Breakdown voltage, blocking voltage	$I_R=100\mu\text{A}$	600			V
$V_F$	Forward voltage	$I_F=30\text{A}$		1.4	1.5	V
		$I_F=30\text{A}, T_J=150^\circ\text{C}$			1.3	V
$I_R$	Reverse leakage current	$V_R=600\text{V}$			500	nA
		$V_R=600\text{V}, T_J=150^\circ\text{C}$			500	uA
CT	Junction capacitance	$V_R=600\text{V}$		14		pF

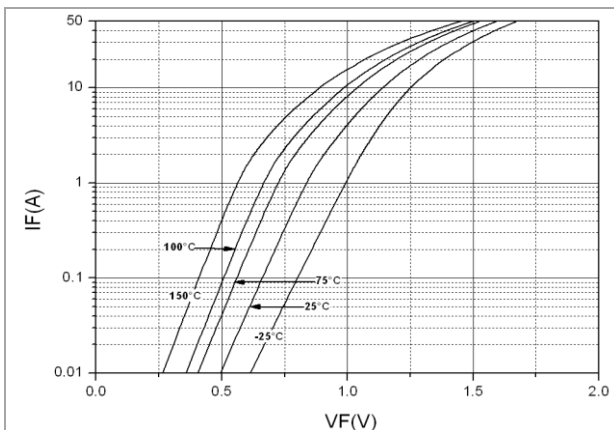
## DYNAMIC RECOVERY CHARACTERISTICS (T<sub>J</sub>= 25 °C unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I <sub>rrm</sub>	Peak recovery current	I <sub>F</sub> =30A, di/dt=200A/us, V <sub>R</sub> =100V		3.6		A
T <sub>rr</sub>	Reverse recovery time			41		ns
Q <sub>rr</sub>	Reverse recovery Charge				80	

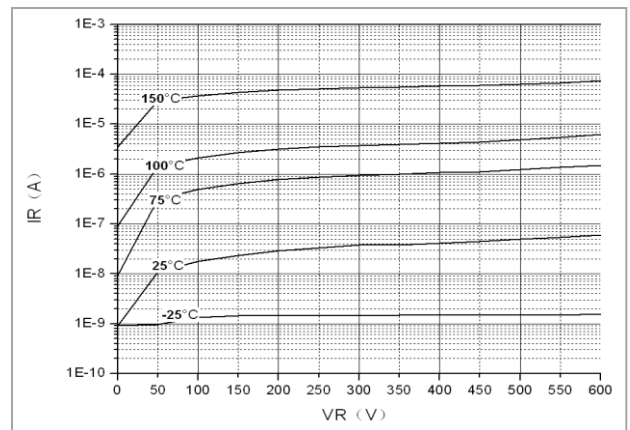
## THERMAL - MECHANICAL SPECIFICATIONS

Symbol	Parameter	Value	Unit
R <sub>thjc</sub>	Thermal resistance, Junction to case (Per Leg)	0.72	°C/W
R <sub>thjc</sub>	Thermal resistance, Junction to case (Per Package)	0.83	°C/W
R <sub>thja</sub>	Thermal resistance, Junction to ambient(Per Leg)	38.4	°C/W
R <sub>thja</sub>	Thermal resistance, Junction to ambient(Per Package)	36.6	°C/W

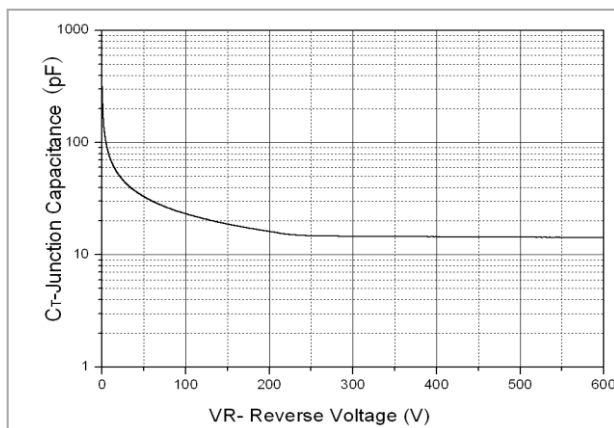
**Fig. 1. Typical Forward Voltage Drop Characteristics**



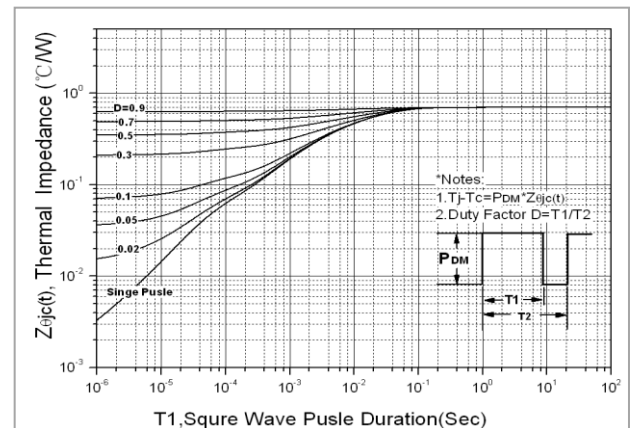
**Fig. 2. Typical Values of Reverse Current vs. Reverse Voltage**



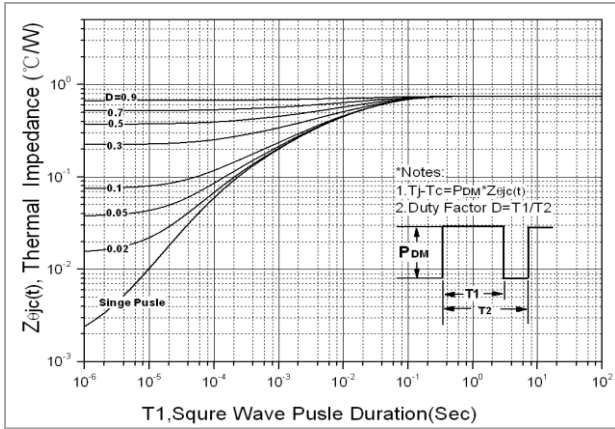
**Fig. 3. Typical Junction Capacitance vs. Reverse Voltage**



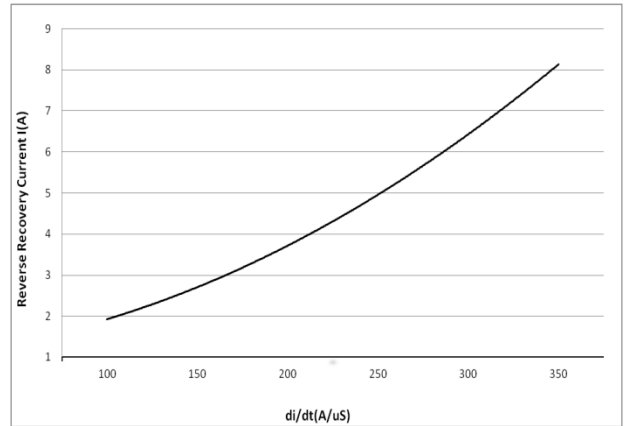
**Fig. 4. Max. Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)**



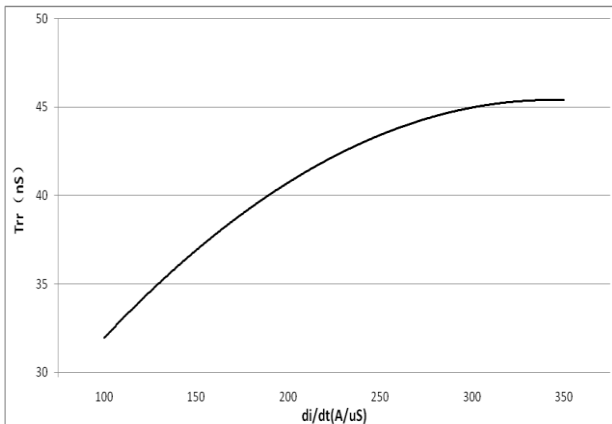
**Fig 5. Max. Thermal Impedance  $Z_{thJC}$  Characteristics (Per Package)**



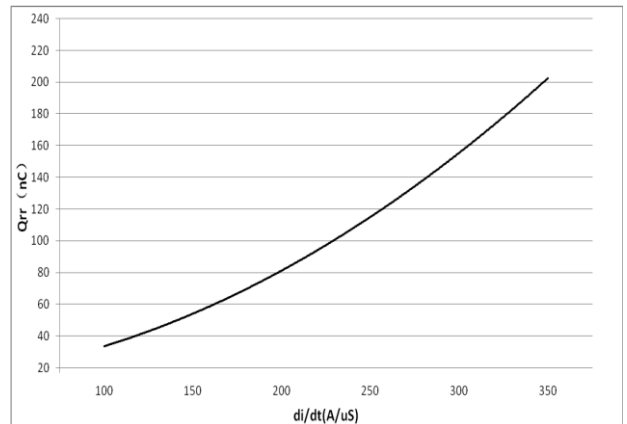
**Fig. 6. Typical Reverse Recovery Current vs. di/dt**



**Fig. 7. Typical Reverse Recovery Time vs. di/dt**



**Fig. 8. Typical Stored Charge vs. di/dt**



**Fig. 9. Reverse Recovery Parameter Test Circuit & waveform**

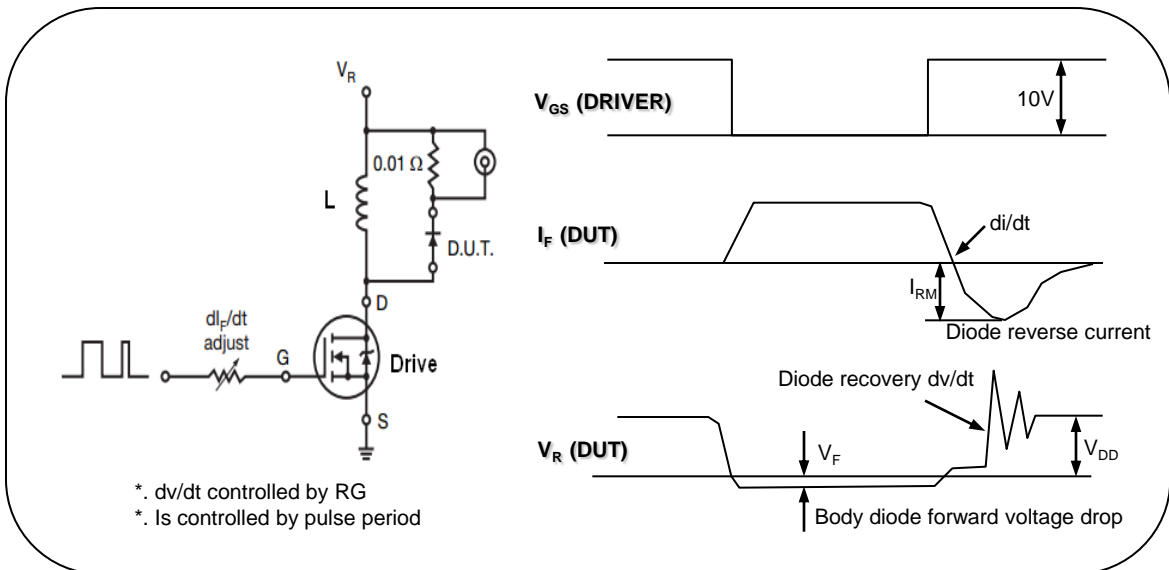


Fig. 10. Unclamped Inductive Test Circuit

